

THGEM gain calculations using Garfield++: Solving discrepancies between simulation and experimental data

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Abstract:

Discrepancies between the measured and simulated gain in Thick Micropatterned gaseous detectors (MPGD), namely THGEM, have been observed by several groups. In order to simulate the electron avalanches and the gain the community relies on the calculations performed in Garfield++, known to produce differences of 2 orders of magnitude in comparison to the experimental data for thick MPGDs.

In this work, simulations performed for Ne/5%CH₄, Ar/5%CH₄ and Ar/30%CO₂ mixtures shows that Garfield++ is able to perfectly describe the experimental data if Penning effect is included in the simulation. The comparison between the number of excitations which may lead to a Penning transfer, is shown for THGEM and GEM, explaining the less pronounced gain discrepancies observed in GEM.

Keywords: Micropattern gaseous detectors (MSGC, GEM, THGEM, RETHGEM, MHSP, MICROPIC, MICROMEGAS, InGrid, etc); Electron multipliers (gas); Charge transport and multiplication in gas; Detector modelling and simulations II (electric fields, charge transport, multiplication and induction, pulse formation, electron emission, etc)

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1 Introduction

The main software tool used for the gas gain simulation in Micropatterned Gaseous Detectors (MPGDs) is Garfield++ [1], a powerful toolkit for the detailed simulation of gaseous detectors and the physical processes occurring on it. It uses Monte Carlo microscopic technique to track electrons in gases on a molecular level, retrieving information about each excited atom: the (x,y,z) position, the time of production and the excitation level [2]. The main drawback of using Garfield++ for gain simulations in Thick Gas Electron Multiplier (THGEM) [3] has been the lower gain obtained when compared with the experimental data, reaching up to 2 orders of magnitude less for measured gains of about 10^5 (see Figure 1). Such discrepancies were generally assumed to be related with the electric field calculation by the finite-elements software or the charging-up of the insulator foils. However, recent results in simulations [4, 5] and experimental data [6] of charging-up in GEM and THGEM have showed that the gain variation due to the insulator charging-up is in the order of a few tens of %, not explaining the 2 orders of magnitude difference. In this work, due to the long calculation time and complexity, charging-up effects were not considered.

One of the input parameters allowed by Garfield++ is the Penning fractions for the gas mixtures, an option which is not often used by users since the data on Penning fractions is sparse and not reliable. The Penning effect occurs in gas mixtures when the energy of an excited atom is higher than the ionization potential of the admixture gas (quencher). If a collision between them occurs, energy transfers are possible resulting in an extra electron [7]. Recently, very detailed and exhaustive studies have been carried out in Penning transfer namely in argon and neon mixtures [7–9].

Our hypothesis is that the Garfield++ gain deficit is due to the non-inclusion of Penning effect in the calculations performed by users. In this work we will evaluate Garfield++'s performance in the thick MPGDs gain calculations by including/excluding the Penning effect and comparing them to experimental data.

2 Method

In this work a 0.4 mm thickness (t) THGEM was simulated. The hole diameter (d) was set to 3 mm with a 0.1 mm rim (rim) and a 0.7 mm pitch (p) being the unitary cell shown in Figure 1. Garfield++'s input electric fields were calculated using Elmer [12], a finite elements electrostatics calculation software, while Gmsh [10, 11], was used as mesh generator for Elmer.

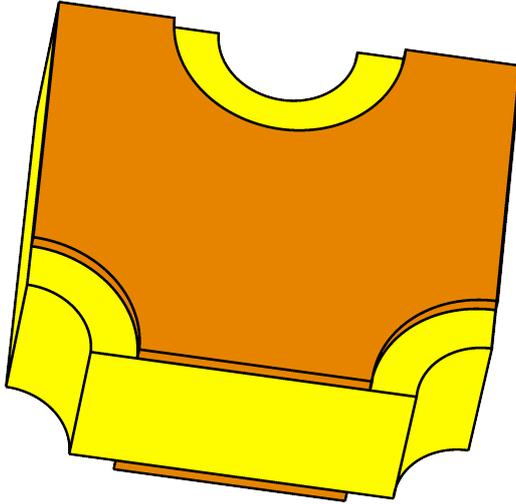


Figure 1. Unitary cell used for the THGEM gain calculations. $t = 0.4$ mm, $p = 0.7$ mm, $d = 0.3$ mm, rim = 0.1 mm.

Calculations in Ne/5%CH₄, Ar/5%CH₄ and Ar/30%CO₂ were performed with and without the inclusion of Penning transfers. Every time the Penning transfers were considered, its rates were set to $r = 0.4$, $r = 0.18$ [8] and $r = 0.57$ [7] respectively to the above listed mixtures.

Two other MPGDs were simulated: the Thick WELL (THWELL) [13, 14] (thickness = 0.4 mm, hole diameter = 0.5 mm, rim = 0.1 mm and pitch = 1.0 mm) in Ne/5%CH₄ and a regular GEM (thickness = 0.05 mm, biconical hole diameter = 0.07/0.05 mm, rim = 0.08 mm and pitch = 0.140 mm) in Ar/30%CO₂. In this case, the Garfield++'s input electric fields were calculated by ANSYS® [15].

For all the cases, the drift and induction regions were set to 5 mm and 2 mm, with electric fields set to 500 V/cm and 2000 V/cm, respectively.

Gas pressure and temperature were considered to be at 760 Torr and 20 °C. For each condition 1000 events were calculated. The gain was assumed to be the average number of electrons produced in the gas per drift electron, i.e., the absolute gain.

3 Results and discussion

Figure 2(a) shows the results of Garfield++'s gain calculations for a 0.4 mm THGEM operating in Ne/5%CH₄, Ar/5%CH₄ and Ar/30%CO₂ when Penning transfers are not considered. For comparison, experimental data for the same THGEM geometry is also shown.

The previously described effect, i.e., the lower calculated gain relatively to the experimental data, is clearly observed. The discrepancies increase with the gain, reaching 2 orders of magnitude when the experimental gains approach 10^5 .

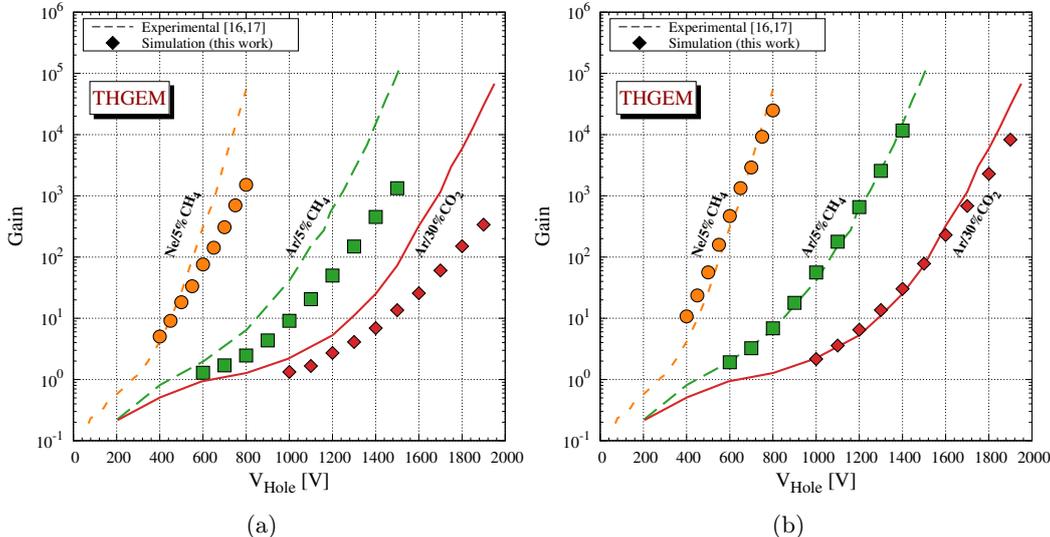


Figure 2. THGEM gain for Ne and Ar based mixtures with CH_4 and CO_2 . Lines are experimental data adapted from [16, 17] while dots are the simulated data. (a) Penning transfers not considered. (b) Penning transfers considered. Error bars are not visible as they are smaller than the dot size.

Calculations for the same gas mixtures were also performed considering Penning transfers. For $\text{Ar}/5\%\text{CH}_4$ a transfer rate $r = 0.18$ taken from [8] was used while for $\text{Ar}/30\%\text{CO}_2$ a value of $r = 0.57$ was set [7]. The value used for $\text{Ne}/5\%\text{CH}_4$ is empirical due to the lack of data and was chosen by performing preliminary tests. The results are plotted in Figure 2(b).

Comparing the data of Figure 2(a) with that of Figure 2(b) we can observe an improvement of the agreement between experimental and simulated data. For $\text{Ar}/5\%\text{CH}_4$ we can observe a good match showing that Garfield++ is able to describe the THGEM gain in this mixture. For $\text{Ar}/30\%\text{CO}_2$ the simulated gain is in good agreement with the experimental one until it reaches a value of 500. After that value the simulation results slightly diverge from the experimental data presenting a deviation by a factor of 2 when the gain reaches $2 \cdot 10^4$. Such difference is explained in [7] as being due to photon feedback (electrons extracted from the cathode or CO_2 ionization by the scintillation photons), which was not included in the simulation. In the case of $\text{Ne}/5\%\text{CH}_4$ we can observe a small deviation between the calculations and the experimental data both for low and high gains. The fact that for low gains the calculations present higher values let us consider that maybe, the $r = 0.4$ value could be an overestimation. By other side, when considering the methodology in ref [17] we may think that this measurement can have not enough precision (at low gains) for a good estimation on the Penning transfer rates. When looking at high gains we can observe a slightly lower values for calculations relatively to the experimental values. In this case there are two possibilities: or the Penning rate is underestimated, or the most probable in our opinion: photon feedback process should be considered, as described in ref [19]. We

wish to claim the reader attention for the fact that $r=0.4$ is just an estimative. A precise work should be done in order to get a concise value.

In order to confirm that the gain discrepancy is not caused by the choice of finite element software or multiplier structure, the same calculations were carried out for a THWELL multiplier and using ANSYS® software. The results are presented in Figure 3 for a Ne/5%CH₄ mixture with and without considering Penning transfers. The difference between the experimental and calculated data when no Penning transfers are considered is clearly observed. However, when a Penning transfer rate of $r=0.4$ is included, the experimental data is in good agreement with the simulation, showing that Garfield++ is able to perform gain calculations in thick multipliers, accurately modelling the experimental results.

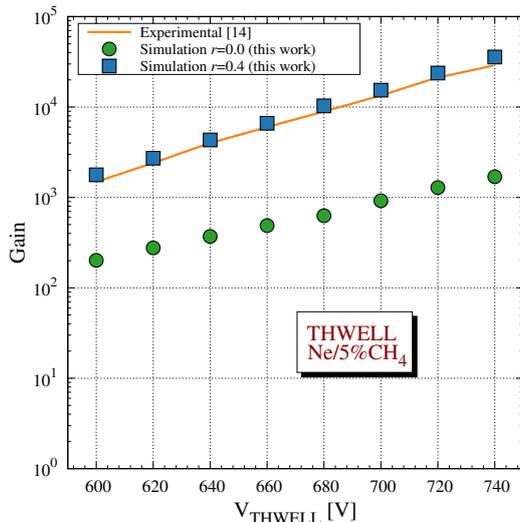


Figure 3. THWELL gain in Ne/5%CH₄. Line is experimental data adapted from [14]. Dots are the simulated data. Error bars are not visible as they are smaller than the dot size.

Figure 4(a) shows Garfield++ gain calculations for GEM and THGEM in a mixture of Ar/30%CO₂, excluding (closed dots) and including (open dots) the Penning transfers. As can be observed, in GEMs the Penning effect in the gain discrepancies is less pronounced. In order to understand this effect we have at look to Garfield++ results keeping in mind that the extra ionization in the gas comes from the excited argon atoms that transfer the energy to CO₂ ionizing it. The result is shown in Figure 4(b), where we have observed a higher number of excitations in THGEM than in GEM, explaining why the differences in gain is lower in GEM than in THGEM when Penning transfers are not considered.

4 Conclusions

Experimental gain measurements in THGEM and THWELL were successfully modelled by using Garfield++, taking into consideration the Penning transfer rates in the simulation. Significant differences were not observed in the results when using different finite elements software in the calculation of electric fields, thereby excluding this cause for the mismatch between experimental and simulated data.

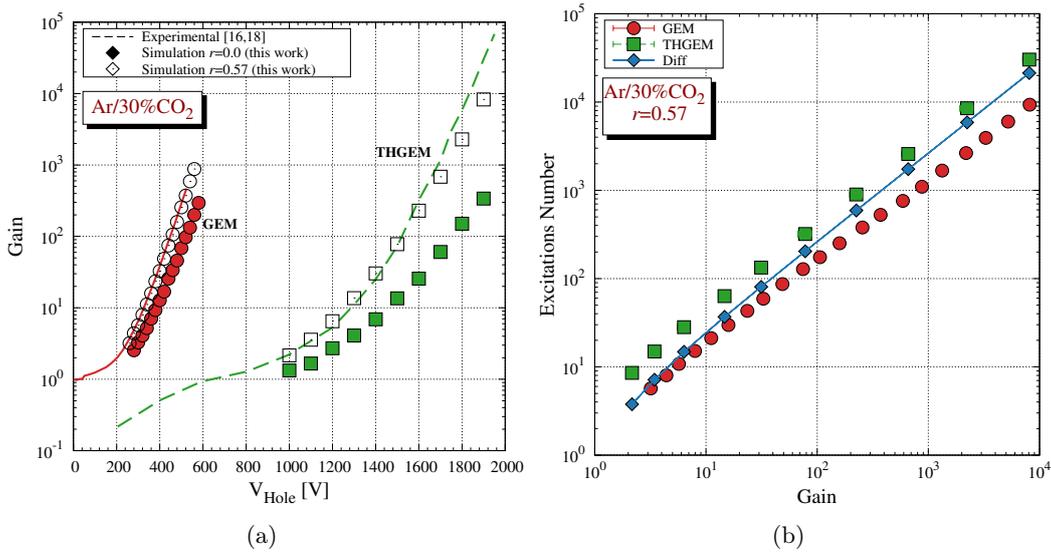


Figure 4. (a) GEM and THGEM gain calculations in Ar/30%CO₂ including and excluding Penning transfers in the simulation - Lines are experimental data adapted from [16, 18]. (b) Number of excitation in GEM and THGEM for the previous mixture. The solid line is the difference between the number of excitations in THGEM and GEM. Error bars are not visible as they are smaller than the dot size.

A Penning transfer rate of $r = 0.4$ was estimated for a Ne/5%CH₄, however, for this case a more detailed study should be performed.

We have also observed a stronger effect of the Penning transfers in THGEM than in GEM. This fact is due to the higher ratio of excitations in THGEM than in GEM. In any case, for correct assessment of the MPGD gains, Penning transfer rates should always be considered.

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References

- [1] H. Schindler, Garfield++. <http://garfieldpp.web.cern.ch/garfieldpp/>, Accessed: 15-06-2016.

- [2] C.A.B. Oliveira et al., A simulation toolkit for electroluminescence assessment in rare event experiments, PLB 703 (2011) 217.
- [3] R. Chechik et al., Thick GEM-like hole multipliers: properties and possible applications, NIMA 535 (2004) 303.
- [4] P.M.M. Correia et al., A dynamic method for charging-up calculations: the case of GEM, JINST 9 (2014) P07025.
- [5] M. Alfonsi et al., Simulation of the dielectric charging-up effect in a GEM detector, NIMA 671 (2012) 6.
- [6] M. Alexeev et al., The gain in Thick GEM multipliers and its time-evolution, JINST 10 (2015) P03026.
- [7] Ö. Şahin et al., High-precision gas gain and energy transfer measurements in Ar-CO₂ mixtures, NIMA 768 (2014) 104.
- [8] Ö. Şahin et al., Penning transfer in argon-based gas mixtures, JINST 5 (2010) P05002.
- [9] Ö. Şahin et al., Systematic gas gain measurements and Penning energy transfer rates in Ne-CO₂ mixtures, JINST 11 (2016) P01003.
- [10] C. Geuzaine and J. Remacle, Gmsh. <http://gmsh.info/>, Accessed: 15-06-2016.
- [11] C. Geuzaine and J. Remacle, Gmsh: A 3-D finite element mesh generator with built-in pre- and post-processing facilities, IJNME 79 (2009) 1309.
- [12] Elmer. <https://www.csc.fi/web/elmer/elmer>, Accessed: 15-06-2016.
- [13] L. Arazi et al., THGEM-based detectors for sampling elements in DHCAL: laboratory and beam evaluation, JINST 7 (2012) C05011.
- [14] L. Arazi et al., Laboratory studies of THGEM-based WELL structures with resistive anode, JINST 9 (2014) P04011.
- [15] ANSYS - Simulation Driven Product Development. <http://www.ansys.com/>, Accessed: 15-06-2016.
- [16] C. Shalem et al., Advances in Thick GEM-like gaseous electron multipliers - Part I: atmospheric pressure operation, NIMA 558 (2006) 475.
- [17] C.D.R. Azevedo et al., Towards THGEM UV photon detectors for RICH on single photon detection efficiency in Ne/CH₄ and Ne/CF₄, JINST 5 (2010) P01002.
- [18] G. Bencivenni et al., The micro-Resistive WELL detector: a compact spark-protected single amplification-stage MPGD, JINST 10 (2015) P02008.
- [19] T. Zerguerras et al., Understanding avalanches in a Micromegas from single-electron response measurement, NIMA 772 (2015) 76.